

PI5A126/PI5A127

Dual, Wide Bandwidth Analog Switches

Features

- Single-Supply Operation (+2V to +6V)
- Rail-to-Rail Analog Signal Dynamic Range
- Low On-Resistance (6-Ohms typ. with 5V supply) Minimizes Distortion and Error Voltages
- On-Resistance Flatness, 3W typ.
- Low Charge Injection Reduces Glitch Errors. Q = 4pC typ.
- High Speed. $t_{ON} = 10$ ns typ.
- Wide-3dB Bandwidth: 230 MHz
- High-Current Channel Capability:>100mA
- TTL/CMOS Logic Compatible
- Low Power Consumption (0.5mW typ.)
- Small MSOP-8 package minimizes board area

Applications

- · Audio, Video Switching and Routing
- Battery-Powered Communication Systems
- Computer Peripherals
- Telecommunications
- Portable Instrumentation
- Mechanical Relay Replacement
- Cell Phones
- PDAs

Description

The PI5A126/PI5A127 are dual SPST (single-pole single-throw) analog switches designed for single supply operation. These high-precision devices are ideal for low-distortion audio, video, signal switching and routing.

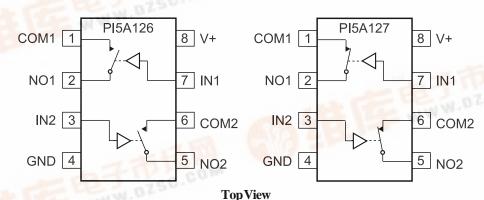
The PI5A126 is a normally open (NO) switch. The switch is open when IN is LOW. The PI5A127 is a normally closed (NC) switch.

Each switch conducts current equally well in either direction when on. When off, they block voltages up to V+.

These switches are fully specified with +5V and +3.3V supplies. With +5V, they guarantee <10-ohm ON-resistance. On-resistance matching between channels is within 2 ohms. On-resistance flatness is less than 5 ohms over the specified range. These switches also guarantee fast switching speeds ($t_{\rm ON} < 20$ ns).

These products are available in 8-pin SOIC and MSOP plastic packages for operation over the industrial temperature range $(-40^{\circ}\text{C to} + 85^{\circ}\text{C})$.

Functional Diagrams, Pin Configurations and Truth Tables



Switches shown for logic "0" input

Logic	PI5A126	PI5A127
1	ON	OFF
0	OFF	ON





Absolute Maximum Ratings

Voltages Referenced to GND	
V_+	
$V_{IN}, V_{COM}, V_{NC}, V_{NO}$ (Note 1)	-0.5 V to V++2V
	or 30mA, whichever occurs first
Current (any terminal except COM	M,NO,NC) 30mA
Current, COM, NO, NC	100mA
(Pulsed at 1ms, 10% duty cycle)	120mA

Thermal Information

Continuous Power Dissipation	
-6(derate7mW/°Cabove+70°C)	550mW
Storage Temperature	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1:

Signals on NC, NO, COM, or IN exceeding V+ or GND are clamped by internal diodes. Limit forward diode current to 30mA.

Caution: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications - Single +5V Supply

 $(V + = +5V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp. (°C)	Min. ⁽²⁾	Typ. ⁽¹⁾	Max. ⁽²⁾	Units
Analog Switch			•				
Analog Signal Range ⁽³⁾	V _{ANALOG}		Full	0		V+	V
On Resistance	D		25		7.2	10	
On Resistance	R_{ON}	$V+ = 4.5V, I_{COM} = -30mA,$	Full			12	
On-Resistance Match	A.D.	V_{NO} or $V_{NC} = +2.5V$	25		0.20	2	
Between Channels ⁽⁴⁾	$\Delta R_{ m ON}$		Full			4	Ω
On-Resistance	D	$V+=5V, \\ I_{COM}=-30mA, \\ V_{NO} \text{ or } V_{NC}=1V, 2.5V, 4V$	25		2.72	3.5	
Flatness ⁽⁵⁾	(- ')		Full			4	
NO or NC Off Leakage	I _{NO(OFF) or}	$V+ = 5.5V, V_{COM} = 0V,$ $V_{NO} \text{ or } V_{NC} = 4.5V$	25		0.18		
Current ⁽⁶⁾	I _{NC(OFF)}		Full	-200		200	
COM Off Leakage Current ⁽⁶⁾	I _{COM(OFF)}	$V+=5.5V, \\ V_{COM}=+4.5V, V_{NO} \\ or V_{NC}=\pm 0V$	25		0.20		nA
Current	` '		Full	-200		200	
COM On Leakage	Ingerior	$V + = 5.5V$, $V_{COM} = +4.5V$	25		0.20		
Current ⁽⁶⁾ ICOM(C	I _{COM(ON)}	V_{NO} or $V_{NC} = +4.5V$	Full	-200		200	



Electrical Specifications - Single +5V Supply (continued)

 $(V + = +5V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp(°C)	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units
Logic Input			•				
Input High Voltage	V _{IH}	Guaranteed logic High Level		2			V
Input Low Voltage	V _{IL}	Guaranteed logic Low Level	F 11			0.8	
Input Current with Voltage High	I _{INH}	$V_{IN} = 2.4V$, all others = $0.8V$	Full	-1	0.005	1	
Input Current with Voltage Low	I _{INL}	$V_{IN} = 0.8V$, all others = 2.4V		-1	0.005	1	
Dynamic							
T O. T			25		7	15	ns
Turn-On Time	ton	X	Full			20	
T Off T	,	$V_{CC} = 5V$, Figure 1	25		1	7	
Turn-Off Time	t _{OFF}		Full			10	
Charge Injection ⁽³⁾	Q	$C_L = 1 \text{nF}, \text{ Vgen} = 0 \text{V},$ $Rgen = 0 \Omega, \text{ Figure } 2$			1.6	10	pC
Off Isolation	OIRR	$R_L = 50\Omega, C_L = 5pF,$ f = 10MHz, Figure 3			-43		15
Crosstalk	Xtalk	$R_L = 50\Omega$, $C_L = 5pF$, $f = 10$ MHz, Figure 4	25		-43		dB
NC or NO Capacitance	C(off)	f = 1kHz, Figure 5			5.5		
COM Off Capacitance	Ccom(off)				5.5		pF
COM On Capacitance	Ccom(on)	f = 1kHz, Figure 6			13		
-3dB Bandwidth	BW	$R_L = 50\Omega$, Figure 7	Full		326		MHz
Distortion	D	$R_{L} = 10$			0.2		%
Supply							
Power-Supply Range	V+			2		6	V
Positve Supply Current	I+	$V+ = 5.5V, V_{IN} = 0V$ or $V_{CC}, V+$ All Channels on or off	Full			1	μА

Notes:

- 1. The algebraic convention, where the most negative value is a minimum and the most positive is a maximum, is used in this data sheet.
- 2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
- 3. Guaranteed by design
- 4. $\Delta R_{ON} = R_{ON} \max R_{ON} \min$.
- 5. Flatness is defined as the difference between the maximum and minimum value of ON-resistance measured.
- 6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- 7. Off Isolation = $20\log_{10} [V_{COM}/(V_{NO} \text{ or } V_{NC})]$. See Figure 3.



$\textbf{Electrical Specifications - Single + 3.3V Supply} (V + = +3.3V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

				11111			
Parameter	Symbol	Conditions	Temp.(°C)	Min. ⁽¹⁾	Typ. ⁽²⁾	Max. ⁽¹⁾	Units
Analog Switch							
Analog Signal Range ⁽³⁾	Vanalog			0		V+	V
On Presistance	_	$V+ = 3V, I_{COM} = -30mA,$	25		12	18	Ω
On-Resistance	R _{ON}	V_{NO} or $V_{NC} = 1.5V$	Full			22	
On-Resistance Match	ADan		25		1	1	
Between Channels ⁽⁴⁾	$\Delta R_{ m ON}$	$V+ = 3.3V, I_{COM} = -30mA,$	Full			2	
On-Resistance Flatness ^(3,5)	D	$V_{NO} \text{ or } V_{NC} = 0.8V, 2.5V$	25		3.5	4	
On-Resistance Flatness (3,5)	R _{FLAT(ON)}		Full			5	
Dynamic							
	ta	$V_{+} = 3.3V, V_{NO}$ or $V_{NC} = 1.5V$, Figure 1	25		14	25	
Turn-On Time	ton		Full			40	ne
Turn Off Turn	t		25		4.5	12	ns
Turn-Off Time	tOFF		Full			20	
Charge Injection ⁽³⁾	Q	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ V, Figure 2	25		1.3	10	pC
Supply							
Supply Current	I+	$V+=3.6V,\ V_{IN}=0V\ or\ V+$ All Channels on or off	Full			1	μΑ



Test Circuits/Timing Diagrams

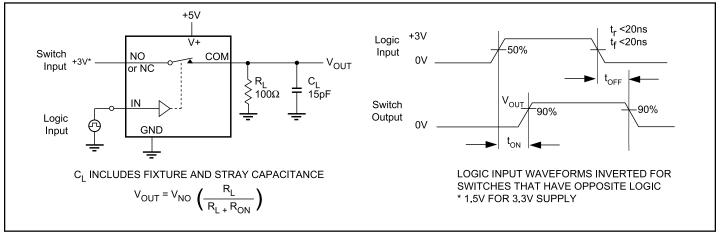


Figure 1. Switching Time

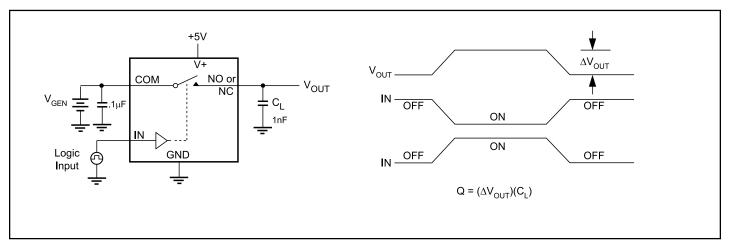


Figure 2. Charge Injection



Test Circuits/Timing Diagrams (continued)

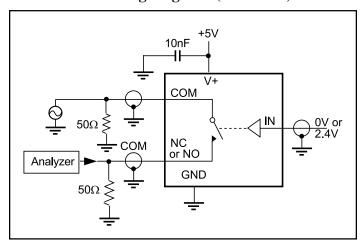


Figure 3. Off Isolation

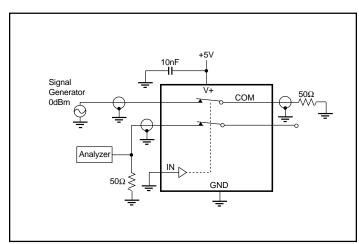


Figure 4. Crosstalk

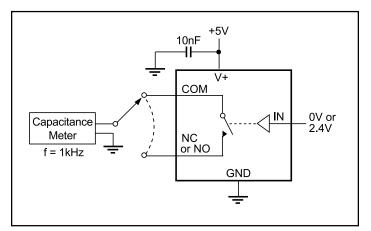


Figure 5. Channel-Off Capacitance

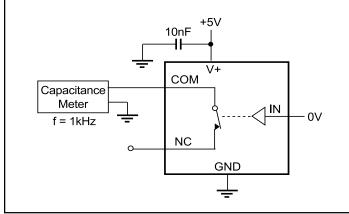


Figure 6. Channel-On Capacitance

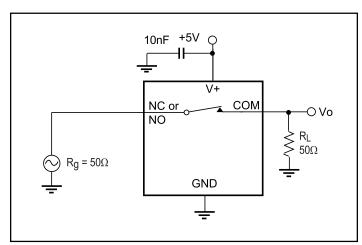


Figure 7. Bandwidth

Ordering Information

P/N	Package
PI5A126W	Narrow SOIC-8
PI5A126UX	MSOP-8
PI5A127W	Narrow SOIC-8
PI5A127UX	MSOP-8